Effect of Spin Coating Speed on Some Optical Properties of ZnO Thin Films

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Abstract

This paper reports the synthesis and characterization of ZnO thin films prepared by sol-gel spin coating technique. The sol-gel was prepared from zinc acetate dehydrate as a precursor, 2-methoxyethanol as a solvent and diethanolamine as a stabilizer, and then deposited on glass substrate using spin coater at the coating speed of 1000 rpm, 2000 rpm, 3000 rpm, 4000 rpm, 5000 rpm and 6000 rpm. After pre-heated at 150˚C, the samples were post-heated at 250˚C and also annealed at 400˚C. X-ray diffraction (XRD) of the films showed polycrystalline hexagonal structure, with (002) orientation as most intense peak having a grain size of 28.1 nm. The absorbance of the film decreases with increasing wavelength and the transmittance was generally high between visible regions from 280 nm - 1200 nm. The ZnO films deposited at a spinning speed of 2000 rpm had highest transmittance of 88% in the visible region from 280 nm - 1200 nm. The energy band gap was found to be in the range of 3.23 - 3.40 eV. The thicknesses of the films decreased with increase in coating speed. Based on these results, ZnO thin films obtained could have useful application in transparent conducting oxide electrode in solar cells.

Keywords

Sol-Gel Spin Coating Technique, Annealing, Grain Size, XRD, Energy Band Gap

1. Introduction

Zinc oxide is an inexpensive n-type semiconductor having direct energy band gap of 3.37 eV which is in two main forms, hexagonal wurtzite \((a = 3.25 \text{ Å} \text{ and } c = 5.2 \text{ Å})\) [1] and cubic zincblende structure. ZnO has also being widely used as an additive in numerous materials and products including plastics, ceramics, glass, cement, lubricants, paints, ointments, adhesives, sealants, pigments, foods (source of Zn nutrient), batteries, ferrites, fire

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retardants and first aid tapes. Thin films of Zinc oxide can be prepared by various techniques; among them are Sputtering [2], Chemical Vapor Deposition (CVD) [3], Laser ablation [4], Sol-gel [5] [6], Spray pyrolysis [7]. The sol-gel spin coating has advantages such as easy control of chemical composition, ability to produce fine structure and fabrication of thin film at low cost. Relatively few works have been done in this direction for ZnO film prepared by sol-gel process [7]. However, adopting spin coating technique can result in growth of a structurally, optically and electrically promising ZnO thin film with appreciable energy band gap. This can partner some other semiconductor materials in improving photovoltaic technology.

Effect of spin coating speed and other deposition parameters on crystalline sizes of ZnO thin films have been reported [8].

In the present work, ZnO films are obtained by sol-gel spin coating technique, its structures are verified and the effect of spin coating speed on some optical properties is studied using X-ray diffractometer and UV-Vis spectroscopy.

2. Experimental Procedure

The glass slides (2.5 cm × 2.5 cm) were washed with an alkali-free detergent and rinsed many times in distilled water then the ultrasonic cleaning of the glass substrates in acetone and methanol and finally the substrate was dry in an oven.

The sol-gel solution were prepared by dissolving 6.5 g of zinc acetate dehydrate in 10 ml of 2-methoxyethanol and stirred continuously for 30 minutes at 60°C until the solution become turbid, di-ethanolamine was added drop by drop under constant stirring until the turbid or milky solution was cleared. The resultant solution was stirred continuously for another 90 minutes until a colorless, homogeneous and transparent solution was obtained. The solution was kept for 72 hours at room temperature for aging and also for optimum viscosity to be obtained.

The sol-gel solution was dropped onto glass substrate, which was rotated at different spin coating speed of 1000 rpm, 2000 rpm, 3000 rpm, 4000 rpm, 5000 rpm and 6000 rpm for 30 s each by using LAURELL WS-400-6NPPSS spin coater. After the deposition, the films were pre heated at 150°C for 3 hours immediately after coating and post heated at 250°C for 6 hours in an oven to evaporate the solvent and remove organic residues. The films were then inserted into a crucible and annealed in air at 400°C for 4 hours. The flow chart showing the procedure for preparing ZnO thin films were shown in Figure 1. The thicknesses of the films were measured with profiler. X-ray diffraction patterns were obtained with a PanalyticalXpert Pro, XRD using the CuKα radiations (λ = 1.54059 Å) in the range of 2θ between 10° and 100°. The optical measurement of the film was carried out at room temperature using Jenway 6405 UV/Vis, spectrophotometer with the wavelength range from 280 nm to 1200 nm.

3. Results and Discussions

3.1. Structural Analysis of Polycrystalline Films

The crystal structure of ZnO film prepared by sol-gel process was investigated through X-ray diffraction (XRD). Figure 2 shows XRD pattern of ZnO thin film deposited on glass substrate and annealed at 400°C. The prominent reflection peaks show that the film is polycrystalline in nature. The lattice constants “a” and “c” of the hexagonal wurtzite structure of ZnO film with (002) orientation can be calculated using Equations (1) and (2) [9].

\[ a = \frac{\sqrt{3} \lambda}{\sin \theta} \]  

\[ c = \frac{\lambda}{\cos \theta} \]  

where \( \lambda \) is the wavelength of the radiation and \( \theta \) is the Bragg’s angle. The values obtained for the unit cell \( a = 3.020 \) Å and \( c = 5.108 \) Å are in good agreement with those reported in the literature. The diffraction peaks correspond to the crystallographic orientations (100), (002), (101) at angles 2θ = 28.006°, 30.15° and 32.962° respectively.
From the XRD spectrum, grain size (D) of the film was calculated using the Debye Scherrer’s formula [9]:

$$D_{\text{sch}} = \frac{K \lambda}{\beta \cos \theta}$$  \hspace{1cm} (3)

where $k$ is a constant to be taken 0.9, $\beta$ is Full Width Half Maximum (FWHM) in radian, $\lambda$ is the wavelength of X-ray used and $\theta$ is Bragg’s angle. The grain size of (002) oriented thin film was calculated to be 28.1 nm. This is very close to the result reported by [7].
3.2. Optical Properties of Polycrystalline ZnO Thin Films

The films thicknesses were measured to be between 127.4 nm and 81.5 nm. The thickness of the film becomes thinner as the spin coating speed increases then the fluid spins off rapidly at the surface of the substrate at a higher coating speed.

Figure 3 displays the optical transmittance spectrum of polycrystalline ZnO thin films annealed at 400°C in air for 4 hours using UV-spectrophotometer from 200 nm - 1200 nm for different coating speed. It can be seen that the transmission values of the film are low at short wavelengths (<380 nm) and high at long wavelengths. This implies that the film behaved as a transparent material at long wavelengths. The average transmittance value is 80% in both 2000 rpm and 3000 rpm samples; this indicates that the film could be used as transparent conducting oxide electrode for solar cell which is similar to reported work of Ali et al. [10]. But in 4000 rpm, 5000 rpm and 6000 rpm samples, the transmittance reduced to 60%. The existence of the interference patterns in the transmittance spectra is due to the film thickness. The interference through the film happens when light reflected from the top surface of a film at specific wavelength and from the bottom of the film at other wavelength. Construction and destruction of wave occur whenever light reflects off a surface of higher refractive index.

Figure 4 displays the absorption spectra for the films at different coating speed, the absorbance of the films decreases with increasing wavelength and decreasing photon energy. For each samples, there is an absorption level that do not differ from one another, their sharp absorption edge is located at 380 nm which is due to the
fact that the ZnO is a direct band gap semiconductor. The absorption spectrum of the ZnO films also reveals that the film has low absorbance in the visible and near infrared regions, while absorbance is high in the ultra violet region.

The energy band gap, $E_g$ of the prepared ZnO thin film can be determined from the graph of $(\alpha h\nu)^2$ against photon energy. The values of $E_g$ change with spin coating speed which show in Figure 5. The corresponding optical band gap of ZnO thin film was estimated by extrapolation of the linear relationship between $(\alpha h\nu)^2$ and $h\nu$ according to the Equation (4).

$$a h\nu = A \left( h\nu - E_g \right)^{1/2}$$

(4)

where $\alpha$ is the absorption coefficient, $h\nu$ is the photon energy, $E_g$ is the optical band gap and $A$ is a constant.

Figure 5 depicts the energy band gap value for ZnO thin film which varies from 3.23 eV - 3.40 eV which is very close to work done by Ilican et al. [7]. The slight deviation in the energy band gap from this work compared with the previous work [7] [10] [11] may be due to the fact that the values of band gap depend on many factors like coating speed (rpm), the granular structure, the nature and concentration of precursors, the structural defects and the crystal structure of the films. The band gap difference between the film and bulk ZnO is due to the grain boundary, the stress and the interaction potentials between defects and the host materials in the films [12].

The films thickness and value of $E_g$ at different coating speed is shown in Table 1.

4. Conclusion

A high quality ZnO thin film on glass substrate has been prepared by sol-gel method using spin coating tech-

![Figure 5. The energy band gap of ZnO thin films at different coating speed.](image)

<table>
<thead>
<tr>
<th>Spin Coating Speed (rpm)</th>
<th>Thickness (nm)</th>
<th>Energy Band Gap (eV)</th>
</tr>
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<tbody>
<tr>
<td>1000</td>
<td>127.40</td>
<td>3.31</td>
</tr>
<tr>
<td>2000</td>
<td>109.10</td>
<td>3.40</td>
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<td>5000</td>
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</tr>
<tr>
<td>6000</td>
<td>81.50</td>
<td>3.25</td>
</tr>
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</table>
nique and also structural and optical properties are verified. The XRD spectrum indicates that the films are of polycrystalline structure with intense peak of (002) orientation. The thickness of the film becomes thinner as the coating speed increase. The average optical transmittance for 2000 rpm and 3000 rpm samples are 80% and their energy band gap is very close to the bulk ZnO (3.37 eV). This present research shows that high transmittance can be achieved at the spin coating speed of 2000 rpm to 3000 rpm which can be used as transparent conducting oxide electrodes. Further work should be done on the effect of other optical properties (like refractive index, extinction coefficient and reflectance) and annealing temperature on spin coated ZnO thin film.

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References


